Effective regulation of the electronic properties of biphenylene network by hydrogenation and halogenation

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Fig. S1 The top views of structures of biphenylene networks functionalized by H (a), F (b), Cl (c) and Br (d) at different concentrations.



Fig. S2 The PBE (black lines) and HSE (red lines) band structures of fluorinated biphenylenes at different fluorine concentration x. The Fermi levels are shown by dashed lines.



Fig. S3 The PBE (black lines) and HSE (red lines) band structures of chlorinated biphenylenes at different chlorine concentration *x*. The Fermi levels are shown by dashed lines.



Fig. S4 The PBE (black lines) and HSE (red lines) band structures of brominated biphenylenes at different bromine concentration *x*. The Fermi levels are shown by dashed lines.